

Refine Search

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L23 and (plasma same (ammonia or "NH.sub.3"))	12

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<u>L24</u>	L23 and (plasma or pecvd)	23	<u>L24</u>
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<i>DB=USPT; PLUR=YES; OP=ADJ</i>			
<u>L5</u>	6045954.pn.	1	<u>L5</u>
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